

BCR5FM-12LB

600V - 5A - Triac Medium Power Use R07DS0960EJ0001 Rev.0.01 Nov 19, 2012

Features

I_{T (RMS)}: 5 A
 V_{DRM}: 600 V

• Tj: 150°C

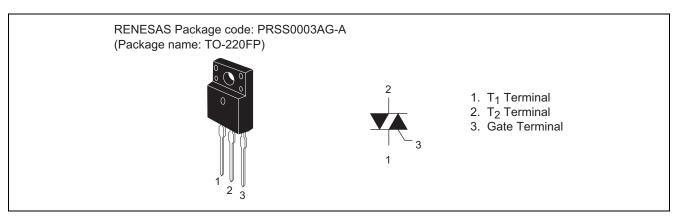
 $\bullet \quad I_{FGTI},\,I_{RGTII},\,I_{RGTIII}\text{: 20 mA (10mA)}^{Note5}$

• Insulated Type

• Planar Passivation Type

Viso: 2000 V

Outline



Applications

Switching mode power supply, small motor control, heater control, solenoid driver, and other general purpose control applications

Maximum Ratings

Parameter	Svmbol	Voltage class	Unit
r ai ainetei	Symbol	12	
Repetitive peak off-state voltage ^{Note1}	V_{DRM}	600	V
Non-repetitive peak off-state voltage ^{Note1}	V_{DSM}	720	V

Parameter	Symbol	Ratings	Unit	Conditions
RMS on-state current	I _{T (RMS)}	5	A	Commercial frequency, sine full wave 360° conduction, Tc = 121°C
Surge on-state current	I _{TSM}	50	A	60Hz sinewave 1 full cycle, peak value, non-repetitive
I ² t for fusion	l ² t	10.4	A ² s	Value corresponding to 1 cycle of half wave 60Hz, surge on-state current
Peak gate power dissipation	P _{GM}	3	W	
Average gate power dissipation	P _{G (AV)}	0.3	W	
Peak gate voltage	V_{GM}	10	V	
Peak gate current	I _{GM}	2	Α	
Junction Temperature	Tj	-40 to +150	°C	
Storage temperature	Tstg	-40 to +150	°C	
Mass	_	1.9	g	Typical value
Isolation voltage Note6	Viso	2000	V	Ta = 25°C, AC 1 minute $T_1 \cdot T_2 \cdot G$ terminal to case

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Electrical Characteristics

Parameter		Symbol	Min.	Тур.	Max.	Unit	Test conditions
Repetitive peak off-state cu	rrent	I _{DRM}	_	_	2.0	mA	Tj = 150°C, V _{DRM} applied
On-state voltage		V _{TM}	_	_	1.8	V	Tc = 25°C, I _{TM} = 7A, instantaneous measurement
Gate trigger voltage ^{Note2}	I	$V_{FGT_{I}}$	_	_	1.5	V	$Tj = 25^{\circ}C, V_D = 6 V, R_L = 6 \Omega,$
	II	V_{RGTI}	_	_	1.5	V	$R_G = 330 \Omega$
	III	V_{RGTIII}	_	_	1.5	V	
Gate trigger curent ^{Note2}	I	I_{FGTI}	_	_	20 Note5	mA	$Tj = 25$ °C, $V_D = 6$ V, $R_L = 6$ Ω,
	II	$I_{RGT_{\mathrm{I}}}$	_	_	20 Note5	mA	$R_G = 330 \Omega$
	III	I_{RGTIII}	_	_	20 Note5	mA	
Gate non-trigger voltage		V_{GD}	0.2	_	_	V	$Tj = 125^{\circ}C, V_D = 1/2 V_{DRM}$
			0.1	_	_	V	$Tj = 150^{\circ}C, V_D = 1/2 V_{DRM}$
Thermal resistance		R _{th (j-c)}			3.8	°C/W	Junction to case ^{Note3}
Critical-rate of rise of off-state		(dv/dt)c	5		_	V/μs	Tj = 125°C
commutation voltage ^{Note4}			1	_	_	V/μs	Tj = 150°C

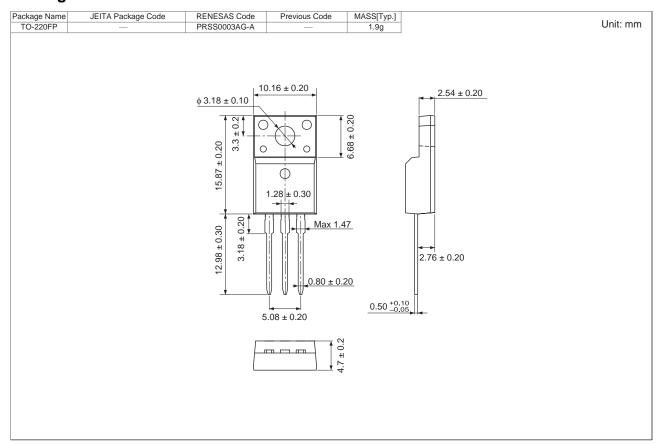
Notes: 1. Gate open.

- 2. Measurement using the gate trigger characteristics measurement circuit.
- 3. The contact thermal resistance $R_{th\ (c\text{-}f)}$ in case of greasing is 0.5°C/W .
- 4. Test conditions of the critical-rate of rise of off-state commutation voltage is shown in the table below.
- 5. High sensitivity ($I_{GT} \le 10$ mA) is also available (I_{GT} item: 1).
- 6. Make sure that your finished product containing this device meets your safe isolation requirements. For safety, it's advisable that heatsink is electrically floating.

Test conditions	Commutating voltage and current waveforms (inductive load)
1. Junction temperature Tj = 125/150°C	Supply Voltage → Time
2. Rate of decay of on-state commutating current (di/dt)c = -2.5A/ms	Main Current (di/dt)c → Time
3. Peak off-state voltage V _D = 400 V	Main Voltage Time (dv/dt)c

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Package Dimensions



Ordering Information

Orderable Part Number	Packing	Quantity	Remark
BCR5FM-12LB#BB0	Tube	50 pcs.	Straight type
BCR5FM-12LB-A8#BB0	Tube	50 pcs.	A8 Lead form

Note: Please confirm the specification about the shipping in detail.

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